



Photocathodes for High Repetition Rate Light Sources

John Smedley, Howard Padmore, Ilan Ben-Zvi

Klaus Attenkofer, Seon Woo Lee, Triveni Rao, Theodore Vecchione, Miguel Ruiz Oses, Xue Liang, Erik Muller, Mengjia Gaowei, Jon Rameau, Peter Johnson, Tianmu Xin, Xiangyun Chang, Erdong Wang, Qiong Wu





Alkali Antimonide and Diamond Amplifier

Materials science-based approach to cathode growth

Cathode chemistry with XPS and XRF/EDX

Cathode structure with XRD and SEM

Diamond defect mapping; understanding the mechanism of emission

Performance with QE mapping, ARPES and momentum measurement

Diagnostics integrated into growth chambers

Universal load-lock to enable growth chamber->gun->analysis

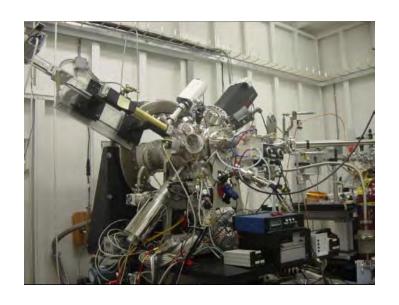
Utilization of user facilities **greatly** expands capabilities Gun, lifetime and exposure tests

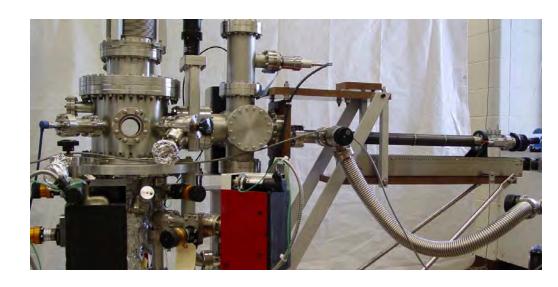
Test cathodes in "real-world" environments

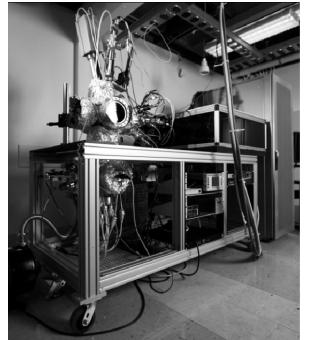
Subsequent analysis will identify defects and failure modes

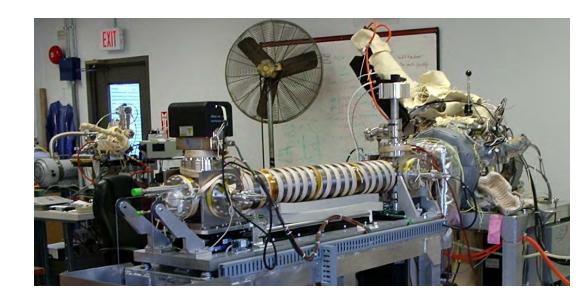
Take the cooking out of making cathodes

Alkali Antominide Growth









K₂CsSb: A cathode with excellent characteristics for accelerator applications



T. Vecchione, 1 I. Ben-Zvi, 2,3 D. H. Dowell, 1,4 J. Feng, 1 T. Rao, 2 J. Smedley, 2 W. Wan, 1 and H. A. Padmore 1,4

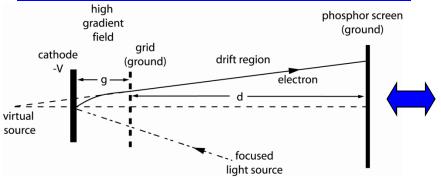
*Lawrence Berkeley National Laburatory, Berkeley, California 94720, USA *Brookhaven National Laboratory, Upton, New York 11973, USA *Stony Brook University, Stony Brook, New York 11794, USA

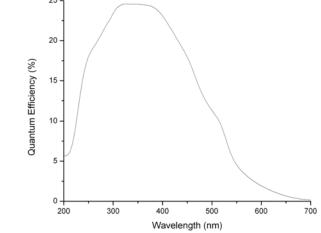
SLAC National Accelerator Laboratory, Menlo Park, California 94025, USA

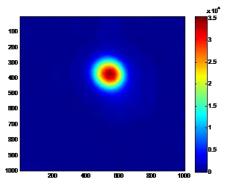
(Received 19 May 2011; accepted 27 June 2011; published online 21 July 2011)

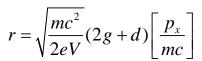
Free-electron lasers and energy recovery linaes represent a new generation of ultra-high brightness electron accelerator based x-ray sources. Photocathodes are a critical performance-limiting component of these systems. Here, we describe the development of photocathodes based on potassium-cesium-antimonide that satisfy many of the key requirements of future light sources. such as robustness, high quantum efficiency when excited with visible light, and low transverse emittance: © 2011 American Institute of Physics. [doi:10.1063/1.3612916]

Fast (msec), high field (4 MV/m; can be > 10 MV/m) measurement of transverse momentum



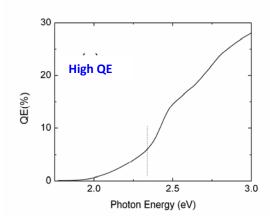


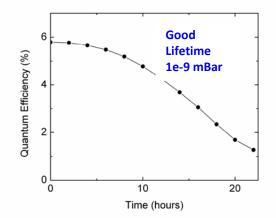


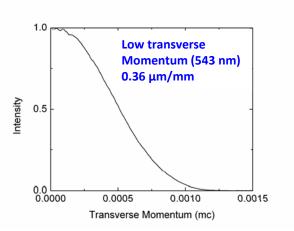


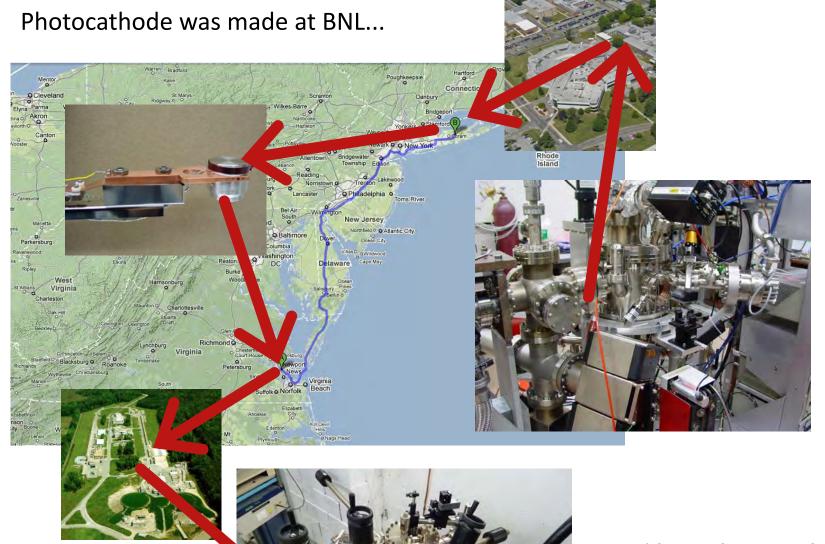
r = radial coord on detector g - cathode to grid distance d = drift distance

Instrumental resolution less than for kT







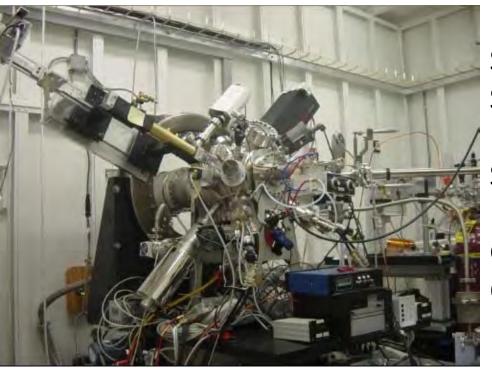


...and brought to JLab for testing.

Long Dark Lifetime!

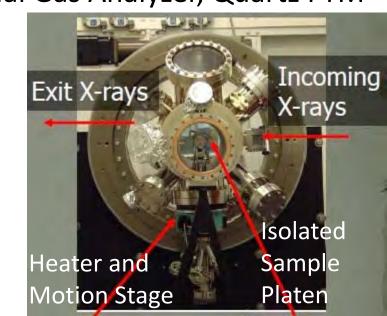
For Details, see Triveni's Poster

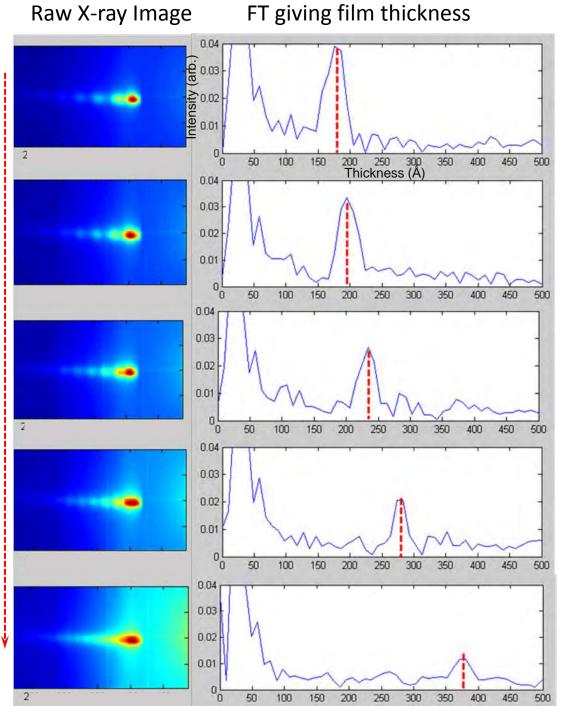
Deposition with In Situ Analysis



UHV system w/ Load Lock
Sb Line Source (evaporation)
Sb Sputtering
K and Cs Alvasources
SAES Getter Sources
Heat Cathode to 800C
Gas cooling
QE Measurement with 532 nm
Residual Gas Analyzer, Quartz FTM

In-Situ Diagnostics (during growth):
Pilatus 100k X-ray camera
XRD for grain size and orientation
in plane and reflection geometry
X-ray fluorescence for stoichiometry and
contamination
XRR for film thickness



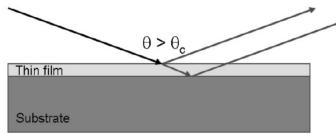


Pilatus 100k detector 4 degrees from normal Grazing incidence X-rays

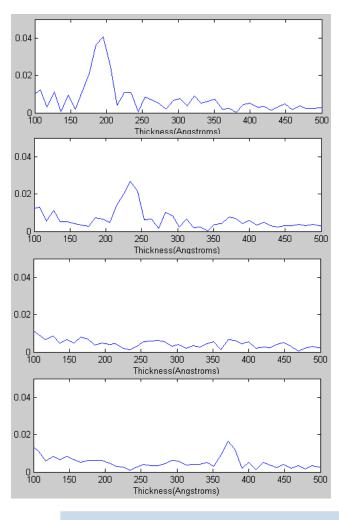
Interference between the top surface and bottom surface reflection

Fourier transform provides film thickness during deposition

SEM measurements gave a final film thickness of 39 nm (compared to 37 nm from XRR)



K-growth on Sb: One Example



Sb-film (18nm)

K-evaporation started

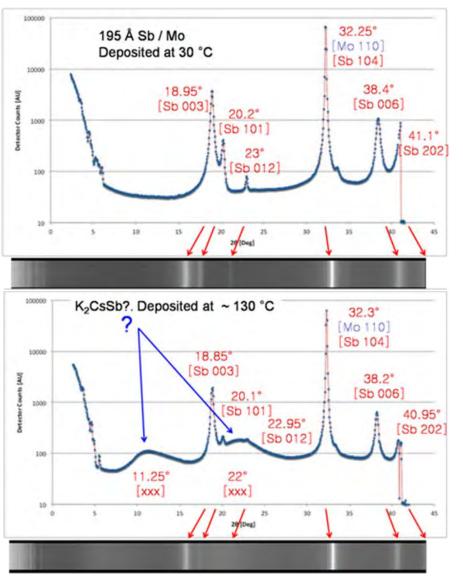
K-evaporation goes on

Final film

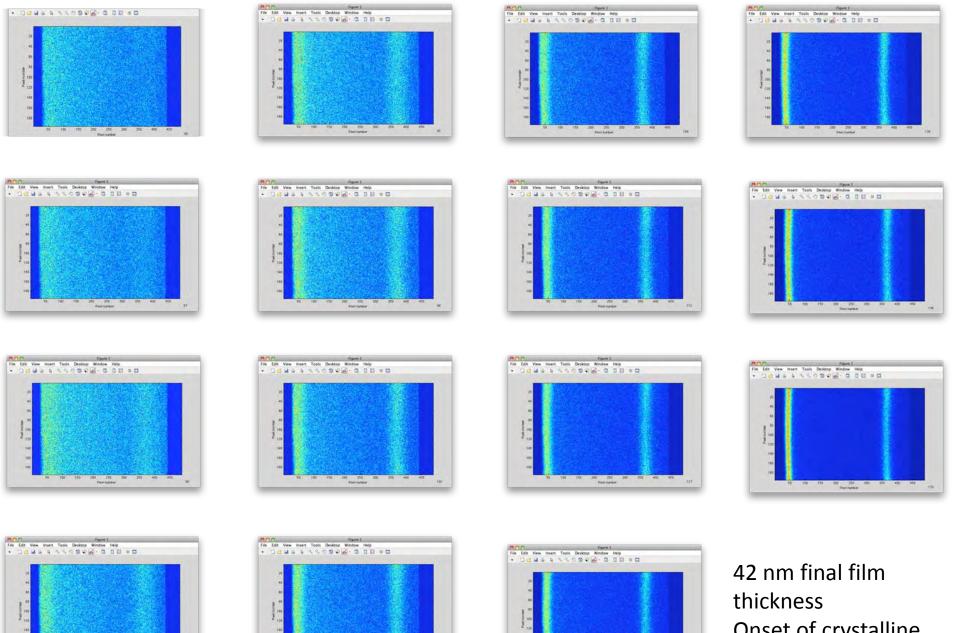
- In-situ sputtered Sb film (18 nm) – begin to observe fringes around 3 nm
- K-evaporation starts:
 - Roughness is increasing
 - Single peak shows that K instantaneously (1s) reacts and intermixes
- Ongoing evaporation of K:
 - Film shows large roughness (no peak)
- Final Film:
 - At 37 nm, roughness has decreased and peak reappears
 - Crystalline phase transition?

Currently in progress: More quantitative analysis and systematic recipe variations

In Situ X-ray Diffraction (XRD)



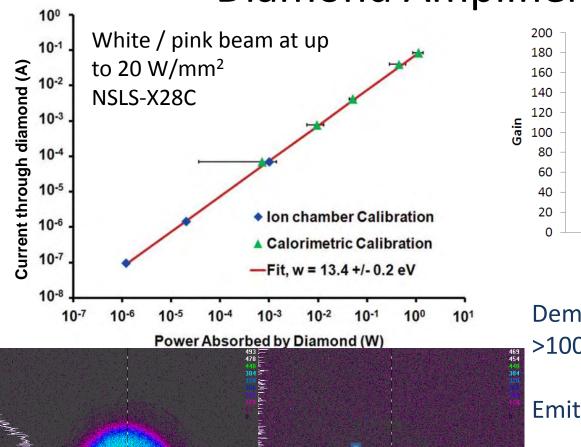
- High indexed peaks disappear:
 - Indication that crystallite gets smaller or very strained
- Sb peaks show reduced intensity
 - Smaller crystals but still Sb-phase present
- Strong background observable:
 - Not clear which Cs_xK_ySb_n-phases are produced
 - Is active cathode material in amorphous phase?
- Combined with XPS results, may suggest this cathode had insufficient K to react all of the Sb

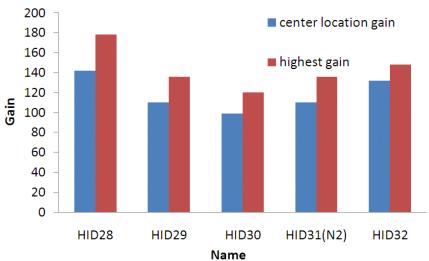


100 150 250 250 300 850 400 450 50 Flori surport 53

Onset of crystalline structure ~8nm

Diamond Amplifier Results





Demonstrated emission and gain of >100 for 7 keV primaries

Emitting ~60% of secondaries

X-ray photons have been used to generate current densities in excess of 20A/cm² with no deviation from response linearity

X. Chang et al., Phys. Rev. Lett. **105**, 164801 (2010)

With focusing

J. Bohon, E. Muller and J. Smedley, J. Synchrotron Rad. 17, 711-718 (2010)

Currently Underway

Diamond

Effect of B doping on emission
Schottky barrier in diamond-metal
interface (XPS)
Amplifier in SRF & NCRF guns

Alkali Antimonide

Determine the effect of microroughness on emittance
Substrate influence
Evaporation vs Sputtering
Optimize the crystal growth
Larger grains -> higher QE?
Improve stoichiometry control
XPS and XRF
New cathode for Jlab DC Gun tests

Next Steps

Cathode tests in the VHF gun and the SRF guns
Lifetime at high current
Failure modes
O₂ and water chemistry
XPS for surface oxidation?

Come to my poster for:

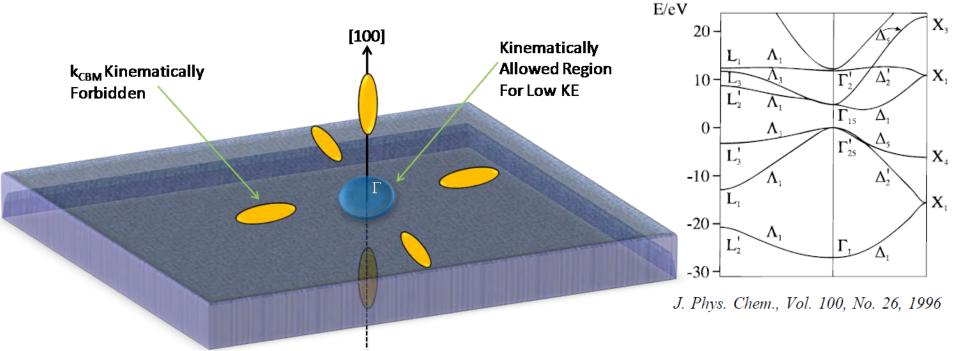
In-situ growth chemistry (XPS) Why does diamond emit?

Publications

E. Wang, et al; Phys. Rev. ST Accel.
Beams **14**, 061302 (2011)
D. A. Dimitrov, et al.; Modeling and
Simulations of Electron Emission from
Diamond-Amplified Cathodes, PAC 2011
T. Vecchione et al; Appl. Phys. Lett. **99**, 034103 (2011)

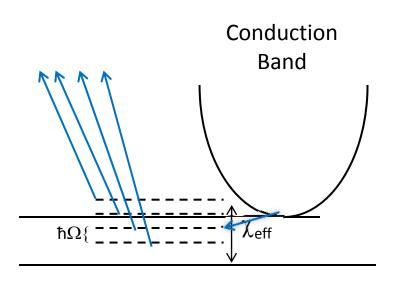
Why Does Diamond Emit?

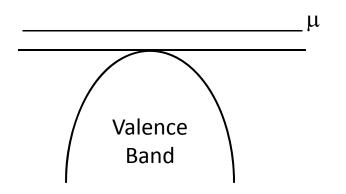
Projection of k-space onto [100] Surface

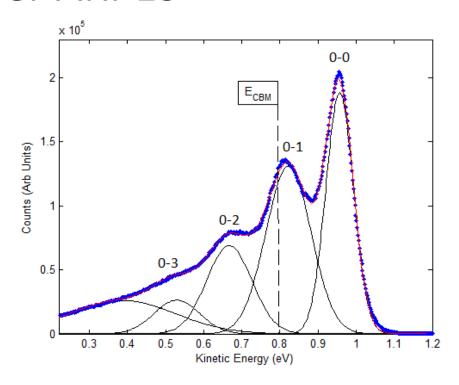


Hydrogen termination causes diamond to have a work function ~1 eV lower than its band gap **but** the band gap is indirect Thus even electrons with energy 1 eV above the conduction band minimum are not in a momentum state capable of emission This is the crux of the problem for Negative Electron Affinity Diamond

6 eV Laser ARPES







- E_F located at 1.662 eV according to Au reference!
- •KE scale referenced to E_{vac} for NEA material; NEA = -0.955 eV
- \bullet Peak spacing 142±5 meV, consistent with the 145 meV energy of optical phonon which connects Γ to Δ

J. D. Rameau, et al., Phys. Rev. Lett. **106**, 137602 (2011)